

EIE341  
Analog Circuits Laboratory

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# Preface

## 0.1 Proper Behavior Guideline

- No food and drink is allowed in the lab for the purpose of safety of both personnel and devices.
- Do not switch on the power to your circuit until the TA/instructor has checked your connection.
- Be serious and active during the class.

## 0.2 Marking Schemes

- Class Performance 10%
- Pre-Lab Question 30%
- Lab Report 60%
  - English 20%
  - Written Style and Format 20%
  - Correctness of Data, Data Analysis 20%

## 0.3 Requirements of Lab Report

- A copy of final lab report is required for each student or group
- The report may be submitted as an electronics copy or a printed copy as requested.
- The report should be written in English only.
- The report is due seven days after the lab class. Late submission within three day after the due date results in 10% deduction per day, late submission after three days after the due date results in zero mark.

The report *should*

- be written with L<sup>A</sup>T<sub>E</sub>X.

- explain the principle and list necessary equations, show the calculation of all theoretical values.
- collect all the test data and do necessary analysis using tables, graphs.
- make comparison between the test data and theoretical values.
- answer all the questions given in the manual, which are normally typed in bold.
- try to explain the reason of some errors and make proper comments and conclusions.

The report *should not JUST*

- repeat the description of experiment procedures.
- copy any figures and tables directly from the lab manual or other publications.
- use exactly same sentences and expressions from the lab manual without any modification.



# Chapter 1

## Diode Circuits I

### 1.1 Objective

- To learn the basic property of a pn diode and a zener diode
- To construct simple diode circuits and verify their performance

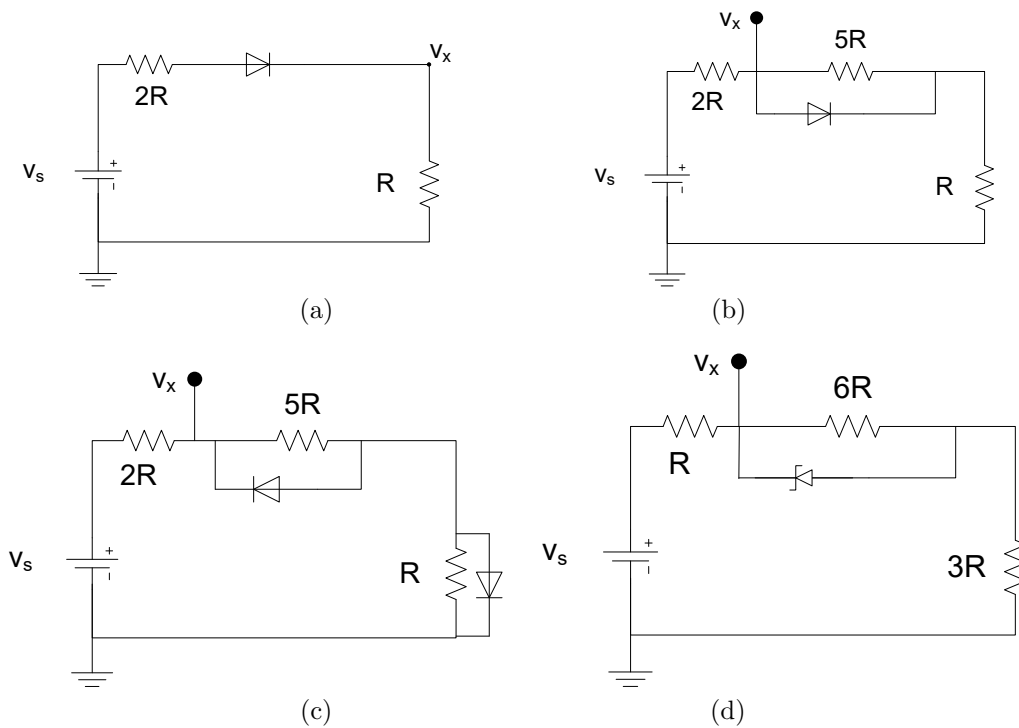


Figure 1.1: Simple diode circuits

## 1.2 Pre-lab Questions

Assuming the built-in voltage of diode is  $V_\gamma$  and the breakdown voltage of a Zener diode is  $V_Z$  in Fig. 1.1, find the relationship between  $V_x$  and  $V_s$  for each circuit theoretically.

## 1.3 Experiment Material

**Equipment:** Digital Multi-Meter, DC power supply, Breadboard

**Components:** Diode (1N4148), Zener diode (1N4728A), schottky diode (SR160), resistors

## 1.4 Part I

1. Pick one regular diode (1N4148) and use the digital multi-meter to identify the polarity of the two terminals, and find the threshold/built-in voltage of the diode
2. Pick one schottky diode (SR160) and repeat the last step
3. Pick one zener diode (1N4728A) and repeat the last step

## 1.5 Part II

Construct the circuits in Fig. 1.1 on a breadboard. For Fig. 1.1(a)~(c),  $R=1000\Omega$  and the type of diode is 1N4148. For Fig. 1.1(d),  $R=50\Omega$  and the type of diode is 1N4728A.

1. For Fig. 1.1(a), measure  $V_x$  when  $V_s$  varies from -1~2 V in a step of 0.2 V, design your own table and record all measured data
2. For Fig. 1.1(b), measure  $V_x$  when  $V_s$  varies from -1~2 V in a step of 0.2 V, design your own table and record all measured data
3. For Fig. 1.1(c), measure  $V_x$  when  $V_s$  varies from -4~7 V in a step of 0.5 V, design your own table and record all measured data
4. For Fig. 1.1(d), measure  $V_x$  when  $V_s$  varies from -4~7 V in a step of 0.5 V, design your own table and record all measured data
5. Please use the measured data to derive:
  - the relationship between  $V_x$  and  $V_s$  data for each circuit and compared them with theoretical calculation;
  - the built-in voltage of the diode used in the circuit;
  - the breakdown voltage of the zener diode used in the circuit

## Chapter 2

# Diodes Circuits II

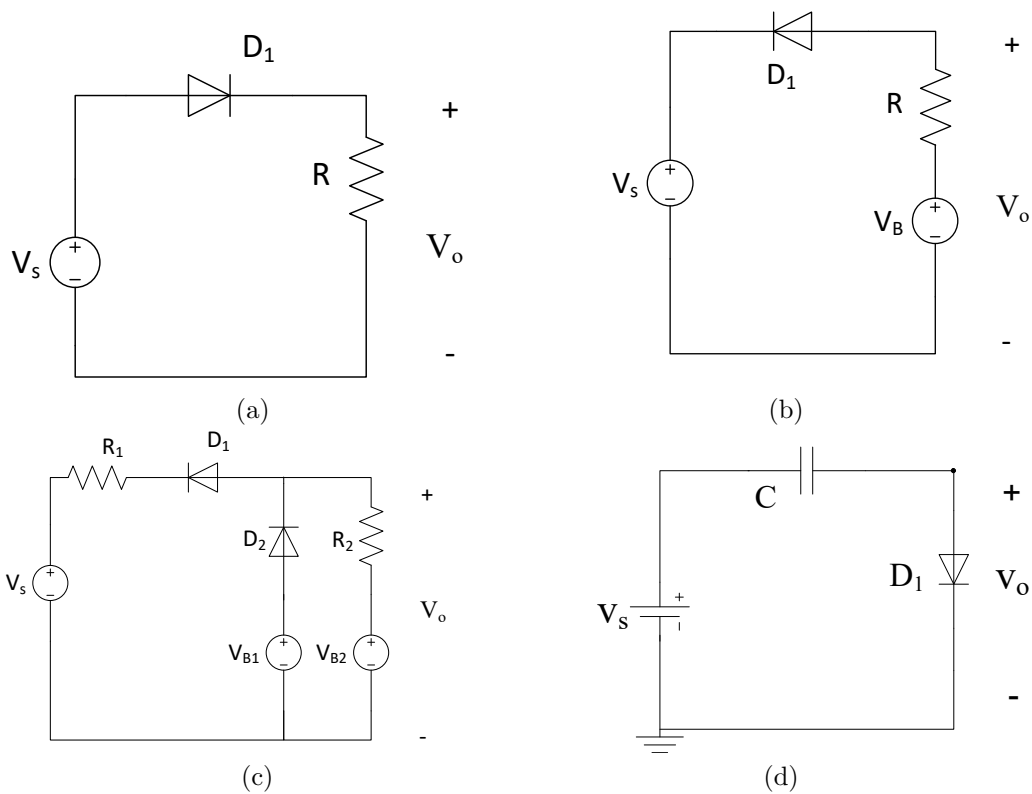


Figure 2.1: Different diode circuits: (a) a half-wave diode rectifier; (b) a clipper circuit with up limit; (c) a clipper circuit with two limits; (d) a clamper circuit.

## 2.1 Objective

- To verify a half-wave diode rectifier circuit
- To verify clipper circuits and clamper circuits

## 2.2 Pre-lab Question

It is assumed that the built-in voltage of diode is  $V_\gamma$  in Fig. 2.1; for Fig. 2.1(b),  $V_B > V_\gamma$ ; for Fig. 2.1(c),  $V_{B2} > V_{B1}$ ; for Fig. 2.1(d),  $V_s = V_P \sin \omega t$ ,  $V_P > V_\gamma$ . Please find the relationship between  $V_o$  and  $V_s$  for each circuit theoretically.

## 2.3 Experiment Material

**Equipment:** Digital multi-meter, DC power supply, Breadboard, Oscilloscope, Function Generator

**Components:** Diode (1N4148), resistors, capacitor

## 2.4 Half-wave Diode Rectifier circuit

1. Construct the circuit of Fig.2.1(a) on a breadboard using the diode (1N4148) and  $R = 1k\Omega$
2. Let  $V_s$  be a sinusoidal signal with 100Hz frequency and 3V peak, using the oscilloscope to observe  $V_s, V_o$  simultaneously, record the plot and make comments on it later in the final report
3. Let  $V_s$  be a triangular signal with 100Hz frequency and 3V peak, using the oscilloscope to observe  $V_s, V_o$  simultaneously, record the plot and make comments on it later in the final report
4. Let  $V_s$  be a dc voltage source, measure  $V_o$  when  $V_s$  varies from -3 to 3 V in a step of 0.2 V, design your own table and record all measured data.
5. **In the final report, find the relationship between  $V_s, V_o$  using measured data graphically and compare it with theoretical calculation, estimate the built-in voltage of the diode**

## 2.5 Clipper circuit I

1. Construct the circuit of Fig.2.1(b) on a breadboard using the diode (1N4148),  $R = 1k\Omega$  and  $V_B = 1V$
2. Let  $V_s$  be a sinusoidal signal with 100Hz frequency and 3V peak, using the oscilloscope to observe  $V_s, V_o$  simultaneously, record the plot and make comments on it later in the final report

3. Let  $V_s$  be a triangular signal with 100Hz frequency and 3V peak, using the oscilloscope to observe  $V_s, V_o$  simultaneously, record the plot and make comments on it later in the final report
4. Let  $V_s$  be a dc voltage source, measure  $V_o$  when  $V_s$  varies from -3 to 3 V in a step of 0.2 V, design your own table and record all measured data.
5. **In the final report, find the relationship between  $V_s, V_o$  using measured data graphically and compare it with theoretical calculation, estimate the built-in voltage of the diode**

## 2.6 Clipper circuit II

1. Construct the circuit of Fig.2.1(c) on a breadboard using the diode (1N4148),  $R_1 = 1k\Omega$ ,  $R_2 = 10k\Omega$  and  $V_{B1} = 5V$ ,  $V_{B2} = 8V$ .
2. Let  $V_s$  be a sinusoidal signal with 100Hz frequency and 10V peak, using the oscilloscope to observe  $V_s, V_o$  simultaneously, record the plot and make comments on it later in the final report
3. Let  $V_s$  be a triangular signal with 100Hz frequency and 10V peak, using the oscilloscope to observe  $V_s, V_o$  simultaneously, record the plot and make comments on it later in the final report
4. Let  $V_s$  be a dc voltage source, measure  $V_o$  when  $V_s$  varies from 0 to 10 V in a step of 0.5 V, design your own table and record all measured data.
5. **In the final report, find the relationship between  $V_s, V_o$  using measured data graphically and compare it with theoretical calculation, estimate the built-in voltage of the diode**

## 2.7 Clamper circuit

1. Construct the circuit of Fig.2.1(d) on a breadboard using the diode (1N4148),  $C=100$  nF.
2. Using the function generator to set  $V_s$  be a sinusoidal signal with 1 kHz frequency and 4V peak, **do not "ON" the output**;
3. On the oscilloscope, connect the CH1 probe to  $V_s$ , the CH2 probe to  $V_o$ ; the voltage scales of Ch1 and Ch2 are all set to 2V/div; press "single" to pause the scope, then press "trigger" to activate trigger menu, set the source to be "CH1" with "rising edge" and the trigger mode to be "normal", adjust the trigger level to approximately 2V;
4. Enable the output of function generator by pressing "ON", observe and record the captured waveforms of  $V_s$  and  $V_o$ , compare them with the theoretical prediction from the pre-lab, estimate the built-in voltage of the diode from the plot.

## Chapter 3

# Diode Rectifier Circuits

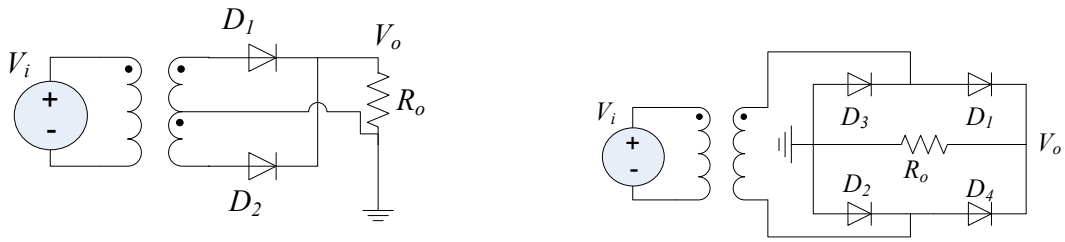


Figure 3.1: (a) a full-wave rectifier with center-tapped transformer; (b) a full-wave bridge rectifier.

### 3.1 Objective

- To verify a full-wave rectifier with center-tapped transformer;
- To verify a full-wave bridge rectifier

### 3.2 Pre-lab Question

It is assumed that the built-in voltage of diode is  $V_\gamma$  in Fig. 3.1, assume  $V_i$  is known, please find the expressions of  $V_o, V_{D_1}, V_{D_2}$  for Fig. 3.1(a);  $V_o, V_{D_1}, V_{D_4}$  for Fig. 3.1(b) theoretically.

### 3.3 Experiment Material

**Equipment:** Digital multi-meter, DC power supply, Breadboard, Oscilloscope, Function Generator

**Components:** Diode (1N4148), resistors

### 3.4 A full-wave diode rectifier with center-tapped transformer

1. Construct the circuit of Fig.3.1(a) on a breadboard using the diode (1N4148) and  $R = 1k\Omega$ , let  $V_i$  be a sinusoidal signal with 100Hz frequency and 3V peak
2. using the oscilloscope to observe  $V_o$ , record the plot and make comments on it later in the final report
3. Using the oscilloscope to observe  $V_{D_1}, V_{D_2}$  simultaneously, record the plot and make comments on it later in the final report
4. Let  $V_i$  be a dc voltage source, measure  $V_o$  when  $V_i$  varies from -3 to 3 V in a step of 0.2 V, design your own table and record all measured data.
5. **In the final report, find the relationship between  $V_i, V_o$  using measured data graphically and compare it with theoretical calculation, estimate the built-in voltage of the diode**

### 3.5 A full-wave bridge diode rectifier

1. Construct the circuit of Fig.3.1(b) on a breadboard using the diode (1N4148) and  $R = 1k\Omega$ , let  $V_i$  be a sinusoidal signal with 100Hz frequency and 3V peak
2. using the oscilloscope to observe  $V_o$ , record the plot and make comments on it later in the final report
3. Using the oscilloscope to observe  $V_{D_1}, V_{D_4}$  simultaneously, record the plot and make comments on it later in the final report
4. Let  $V_i$  be a dc voltage source, measure  $V_o$  when  $V_i$  varies from -3 to 3 V in a step of 0.2 V, design your own table and record all measured data.
5. **In the final report, find the relationship between  $V_i, V_o$  using measured data graphically and compare it with theoretical calculation, estimate the built-in voltage of the diode**

## Chapter 4

# Common-Emitter Current Gain

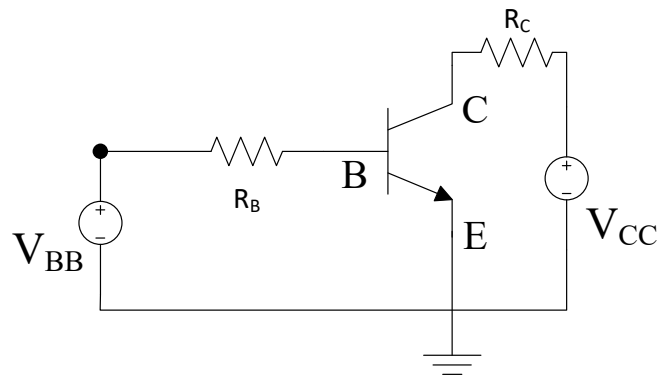


Figure 4.1: Test circuit of a npn BJT

### 4.1 Objective

- To find the Common-Emitter Current Gain of a npn BJT

### 4.2 Pre-lab Question

Review the principle of a npn BJT, the definition of the common-emitter current gain, the dc analysis technique of a BJT circuit.

### 4.3 Experiment Material

**Equipment:** Digital Multi-Meter, DC power supply, Breadboard



Table 4.1: Properties of common-emitter BJT circuit

$V_{BB}=1.0\text{ V}$															
$V_{CC}$	0.1	0.2	0.4	0.6	0.8	1.0	2.0	3.0	4.0	5.0	6.0	7.0	8.0	9.0	10.0
$V_{BE}$															
$V_{CE}$															

**Components:** BJT, resistors

## 4.4 Procedures

Construct the circuit in Fig. 4.1 with a npn BJT (2N3904),  $R_B = 56k\Omega$ ,  $R_C = 1k\Omega$

- Measure the actual values of  $R_B$ ,  $R_C$ ;
- Set  $V_{BB} = 1.0\text{V}$  and vary  $V_{CC}$  from 0 to 10 V, then measure  $V_{CC}$ ,  $V_{BE}$ ,  $V_{CE}$ , fill Table 4.1.
- When  $V_{BB} = 1.3, 1.7, 2.0\text{ V}$ , repeat the above procedures and using the similar tables
- In the final report,
  1. For each different  $V_{BB}$ , find the average of  $V_{BE}$  and  $I_B$  can be found; then calculate  $I_C$  using measured  $V_{CE}$  at different  $V_{CC}$ ;
  2. For each different  $V_{BB}$ , plot the relationship between  $V_{CE}$  and  $I_C$  for different  $I_B$
  3. With the help of plots, identify the boundary points between forward-active and saturation mode, estimate the values of Early voltage  $V_A$  and the common-emitter current gain  $\beta$

## Chapter 5

# Operation Modes of Bipolar Junction Transistor

### 5.1 Objective

- To test the different operation modes of a npn BJT
- To test the different operation modes of a pnp BJT

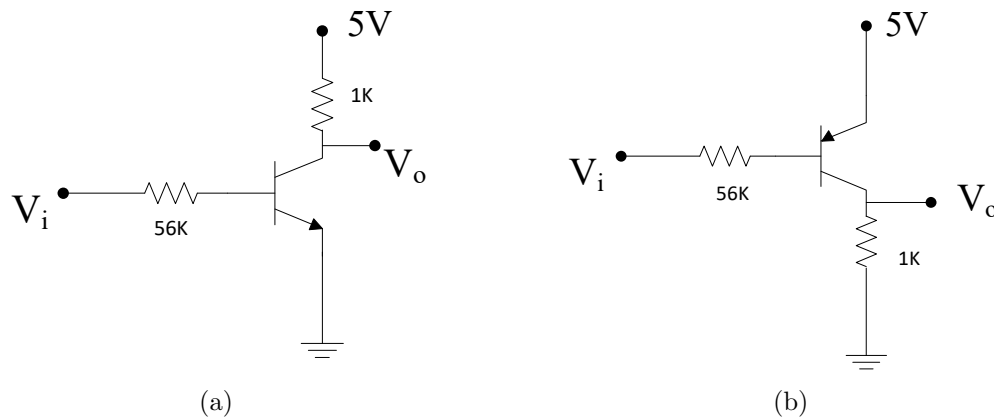


Figure 5.1: Operation modes of: (a) a npn BJT circuit; (b) a pnp BJT circuit.

### 5.2 Pre-lab Question

- In Fig. 5.1(a), derive the relationship between  $V_i$  and  $V_o$  if  $V_{BEon}$  is 0.6 and  $\beta$  is 200
- In Fig. 5.1(b), derive the relationship between  $V_i$  and  $V_o$  if  $V_{EBon}$  is 0.6 and  $\beta$  is 200

## 5.3 Experiment Material

**Equipment:** Digital Multi-Meter, DC power supply, Breadboard

**Components:** BJT, resistors

## 5.4 A npn BJT

- Construct the circuit in Fig. 5.1(a) using a 2N3904 npn BJT
- Measure  $V_o$  when  $V_i$  varies from 0 to 5V, design your own table and record all necessary data
- Derive the relationship between  $V_i$  and  $V_o$  graphically, estimate  $\beta$  and  $V_{BEon}$ , identify the mode of the npn BJT in different operation regions
- Compare the experimental results with the pre-lab solution and explain any difference

## 5.5 A pnp BJT

- Construct the circuit in Fig. 5.1(b) using a 2N3906 pnp BJT
- Measure  $V_o$  when  $V_i$  varies from 0 to 5V, design your own table and record all necessary data
- Derive the relationship between  $V_i$  and  $V_o$  graphically, estimate  $\beta$  and  $V_{EBon}$ , identify the mode of the pnp BJT in different operation regions
- Compare the experimental results with the pre-lab solution and explain any difference

## Chapter 6

# A Common-Emitter BJT Amplifier

### 6.1 Objective

- To measure the quiescent-point of a common-emitter BJT amplifier
- To evaluate the small-signal amplification function of a common-emitter amplifier

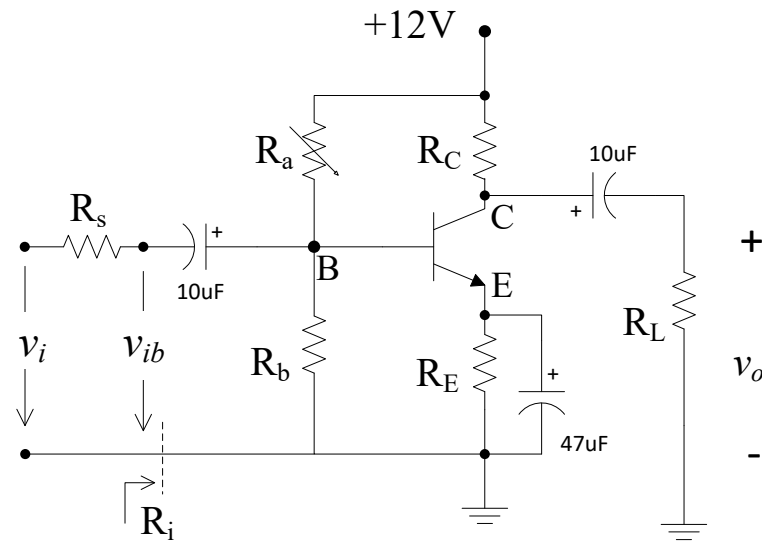


Figure 6.1: A common-emitter amplifier.

## 6.2 Pre-lab Question

In Fig. 6.1, assuming  $V_{BEQ} = 0.65\text{V}$ ,  $\beta = 160$ ,  $R_s = 2.0\text{k}\Omega$ ,  $R_a = 56\text{k}\Omega$ ,  $R_b = 27\text{k}\Omega$ ,  $R_C = 1.0\text{k}\Omega$ ,  $R_E = 1.5\text{k}\Omega$ , (45k, 25k, 1k, 1k)

- Do dc analysis of the amplifier to find  $I_{BQ}$ ,  $I_{CQ}$ ,  $I_{EQ}$ ,  $V_B$ ,  $V_C$ ,  $V_E$ ,  $V_{CEQ}$ .
- Do ac analysis of the amplifier to find  $A_v$ ,  $R_i$ ,  $R_o$ .

## 6.3 Experiment Material

**Equipment:** Digital Multi-Meter, DC power supply, Breadboard, Function Generator, Oscilloscope

**Components:** BJT 2N3904, resistors, capacitor

## 6.4 DC Analysis

- Construct the circuit in Fig. 6.1 using a npn BJT (2N3904) and  $R_L = \infty$
- Let  $v_i$  to be zero (i.e. short it to the ground), use the multi-meter to measure three terminal voltages of the BJT  $V_B$ ,  $V_C$ ,  $V_E$  and calculate  $I_{BQ}$ ,  $I_{CQ}$ ,  $I_{EQ}$  and  $\beta$ , design your own table and record the data
- Compare the experimental results with the pre-lab solution and explain any difference, estimate the actual  $\beta$

## 6.5 AC Analysis: Voltage Gain

- Let  $v_i$  to be a sinusoidal signal (1000 Hz, 0.5V peak) and  $R_L = 300\text{k}\Omega$ , observe input and output voltages with the oscilloscope and record the plot.
- Now reduce the amplitude of  $v_i$  until that the output voltage is not distorted, record the particular amplitude of  $v_i$  as  $V^*$ , record the plots and use the digital multi-meter to measure the rms value of  $v_{ib}$  and  $v_o$ .
- Vary the input voltage amplitude from  $V^*$  to its 80%, 60%, 40% and 20% respectively, repeat the last step
- Calculate the voltage gain  $A_v = v_o/v_{ib}$  for each case above and fill Table 6.1.
- In the final report, answer the following questions:
  1. Compare the experimental results with the pre-lab solution and explain any difference
  2. when the distortion emerges, which mode: saturation or cut-off does the BJT enter into? Then, should  $R_a$  be increased or decreased to enlarge the linear amplification range?

## 6.6 AC Analysis: Input Resistance

- Let  $v_i$  to be a 1000 Hz sinusoidal signal with the amplitude of  $V^*$  and  $R_L = 300k\Omega$ , make sure the output voltage is not distorted with the help of the oscilloscope
- Use the digital multi-meter to measure the rms values of  $v_{ib}$  and  $v_i$ , record the two values to calculate the input resistance  $R_i$  and fill Table 6.2.
- Compare the experimental results with the pre-lab solution and explain any difference

## 6.7 AC Analysis: Output Resistance

- Let  $v_i$  to be a 1000 Hz sinusoidal signal with the amplitude of  $V^*$ , make sure the output voltage is not distorted with the help of the oscilloscope
- Use the digital multi-meter to measure the rms values of output voltage  $v_o$  when  $R_L = 300k\Omega$  (light-load) and when  $R_L = 2k\Omega$  (heavy-load) respectively, record the two values to calculate the output resistance  $R_o$  and fill Table 6.2.
- Compare the experimental results with the pre-lab solution and explain any difference

Table 6.1: Voltage Gain

$V_{ib}$				
$V_o$				
$A_v$				

Table 6.2: Input/output Resistance

$R_s=470K, R_i =$		$R_o=$	
$V_i =$	$V_{ib} =$	$R_L = 300K, V_o =$	$R_L = 1K, V_o =$

## Chapter 7

# A Common-Collector BJT Amplifier

### 7.1 Objective

- To measure the quiescent-point of an emitter follower
- To evaluate the small-signal amplification function of an emitter follower

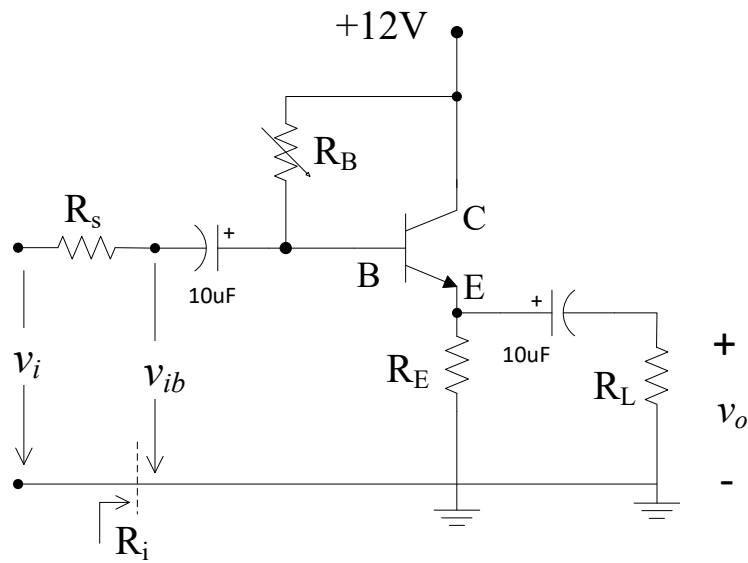


Figure 7.1: A common-collector BJT amplifier/emitter follower.

## 7.2 Pre-lab Question

In Fig. 7.1, assuming  $V_{BEQ} = 0.6\text{V}$ ,  $\beta = 160$ ,  $R_s = 10\text{k}\Omega$ ,  $R_B = 56\text{k}\Omega$ ,  $R_E = 1\text{k}\Omega$ ,

- Do dc analysis of the amplifier to find  $I_{BQ}$ ,  $I_{CQ}$ ,  $I_{EQ}$ ,  $V_B$ ,  $V_C$ ,  $V_E$ ,  $V_{CEQ}$ .
- Do ac analysis of the amplifier to find  $A_v$ ,  $R_i$ ,  $R_o$ .

## 7.3 Experiment Material

**Equipment:** Digital Multi-Meter, Breadboard, Function Generator, Oscilloscope, DC power supply

**Components:** BJT 2N3904, resistors, capacitor

## 7.4 DC Analysis

- Construct the circuit in Fig. 7.1 using a npn BJT (2N3904) and  $R_L = 300\text{k}\Omega$
- Let  $v_i$  to be zero (i.e. short it to the ground), use the digital multi-meter to measure the three terminal voltages of the BJT  $V_B$ ,  $V_C$ ,  $V_E$  and calculate  $I_{BQ}$ ,  $I_{CQ}$ ,  $I_{EQ}$  and  $\beta$ , design your own table and record the data
- Compare the experimental results with the pre-lab solution and explain any difference

## 7.5 AC Analysis: Voltage Gain

- Let  $v_i$  to be a sinusoidal signal (1000 Hz, 5V peak) and  $R_L = 300\text{k}\Omega$ , observe input and output voltages with the oscilloscope and record the plot.
- Now reduce the amplitude of  $v_i$  until that the output voltage is not distorted, record the particular amplitude of  $v_i$  as  $V^*$ , use the digital multi-meter to measure the rms value of  $v_{ib}$  and  $v_o$  and record the plot
- Vary the input voltage amplitude from  $V^*$  to its 80%, 60%, 40% and 20% respectively, repeat the last step
- Calculate the voltage gain  $A_v = v_o/v_{ib}$  for each case above and fill Table 7.1
- In the final report, answer the following questions:
  1. Compare the experimental results with the pre-lab solution and explain any difference
  2. when the distortion emerges, which mode: saturation or cut-off does the BJT enter into? Then, should  $R_B$  be increased or decreased to enlarge the linear amplification range?



## 7.6 AC Analysis: Input Resistance

- Let  $v_i$  to be a 1000 Hz sinusoidal signal with the amplitude of 1 V, make sure the output voltage is not distorted with the help of the oscilloscope
- Use the digital multi-meter to measure the rms values of  $v_{ib}$  and  $v_i$ , record the two values to calculate the input resistance  $R_i$  and fill Table 7.2
- Compare the experimental results with the pre-lab solution and explain any difference

## 7.7 AC Analysis: Output Resistance

- Let  $v_i$  to be a 1000 Hz sinusoidal signal with the amplitude of 1 V, make sure the output voltage is not distorted with the help of the oscilloscope
- Use the digital multi-meter to measure the rms values of output voltage  $v_o$  when  $R_L = 300k\Omega$  and when  $R_L = 1k\Omega$  respectively, record the two values to calculate the output resistance  $R_o$  and fill Table 7.2.
- Compare the experimental results with the pre-lab solution and explain any difference

Table 7.1: Voltage Gain

$V_{ib}$				
$V_o$				
$A_v$				

Table 7.2: Input/output Resistance

$R_s=470K, R_i =$		$R_o=$	
$V_i =$	$V_{ib} =$	$R_L = 300K, V_o =$	$R_L = 1K, V_o =$

## Chapter 8

# Properties of a n-channel enhancement MOSFET

### 8.1 Objective

- To find the voltage-current characteristics of a n-channel enhancement MOSFET
- To evaluate different operation modes of a n-channel enhancement MOSFET

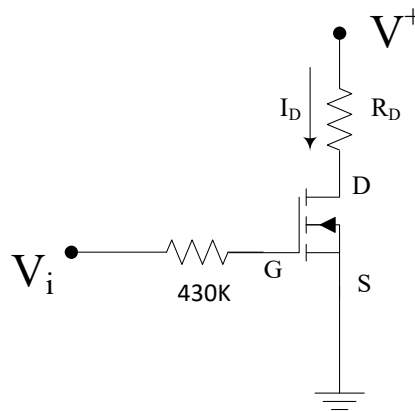


Figure 8.1: Test circuit of a N-channel enhancement MOSFET

### 8.2 Pre-lab Question

In Fig. 8.1, assuming  $V^+ = 12\text{V}$ ,  $R_D = 470\Omega$ ,  $V_{TN} = 1.40\text{V}$ ,  $K_n = 80\text{mA/V}^2$ , find the relationship between  $V_i$  and  $V_{DS}$

### 8.3 Experiment Material

**Equipment:** Digital Multi-Meter, DC power supply, Breadboard

**Components:** MOSFET, resistors, capacitor

### 8.4 Part I

Construct the circuit in Fig. 8.1 with a N-channel enhancement MOSFET (2N7000),  $V^+ = 12.0V$ ,  $R_D = 470\Omega$

- Let  $V_i$  to vary from 0 to 3.0 V in small step, measure  $V_{GS}$ ,  $V_{DS}$ , fill Table 8.1, please take more measurements when  $V_i$  is in the range of 1.1-2.2V
- In final report, plot the relationship between  $V_{GS}$ ,  $V_{DS}$ ; plot the relationship between  $V_{GS}$  and  $I_D$ ; plot the relationship between  $V_{GS}$  and  $\sqrt{I_D}$ , using the plot and curve interpolation technique to find  $V_{TN}$  and  $K_n$

Table 8.1: Estimation of parameters for a MOSFET

$V_i$	0.5																	3.2
$V_{DS}$																		
$V_{RD}$																		
$I_D = \frac{V_{RD}}{R_D}$																		

### 8.5 Part II

Construct the circuit in Fig. 8.1 with a N-channel enhancement MOSFET (2N7000),  $R_D = 470\Omega$

- When  $V_i = 1.6V$ , increase  $V^+$  from 0 in small step, fill Table 8.2 , stop until  $V_{DS}$  approaches 5 V
- When  $V_i = 2.0, 2.4, 2.8V$ , repeat the above procedures
- In final report, plot the relationship between  $V_{DS}$  and  $I_D$  for different  $V_{GS}$ ; identify the boundary points between saturation and non-saturation mode in the plot, estimate the value of  $V_A$  from the plot

Table 8.2: Transfer characteristics of a MOSFET

$V_i=2.6V$																
$V_+$																
$V_{DS}$																
$V_{RD}$																
$I_D = \frac{V_{RD}}{R_D}$																
$V_i=2.8V$																
$V_+$																
$V_{DS}$																
$V_{RD}$																
$I_D = \frac{V_{RD}}{R_D}$																
$V_i=3.0V$																
$V_+$																
$V_{DS}$																
$V_{RD}$																
$I_D = \frac{V_{RD}}{R_D}$																
$V_i=3.2V$																
$V_+$																
$V_{DS}$																
$V_{RD}$																
$I_D = \frac{V_{RD}}{R_D}$																

## Chapter 9

# A Common-Source Amplifier

### 9.1 Objective

- To measure the quiescent-point of a common-source amplifier
- To evaluate the small-signal amplification function of a common-source amplifier

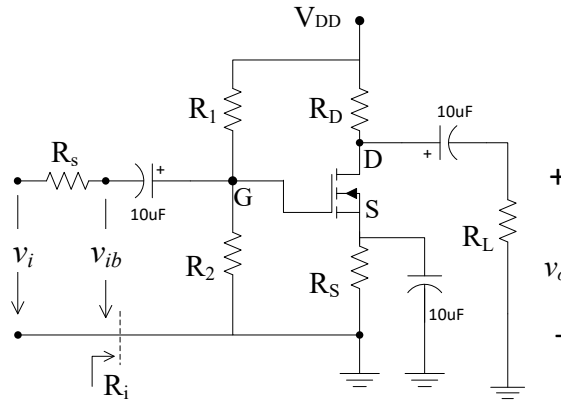


Figure 9.1: A common-source MOSFET amplifier.

### 9.2 Pre-lab Question

In Fig. 9.1, the model of MOSFET is 2N7000 (The parameters of 2N7000 are from last lab).  $V_{DD} = 10V$ ,  $R_1 = 100k\Omega$ ,  $R_D = 200\Omega$ , find  $R_2$ ,  $R_S$  so that  $I_{DQ} = 20mA$ ,  $V_{DSQ} = 4V$ . Let  $R_S = 4700\Omega$  and calculate the small-signal properties of the common-source amplifier:  $A_v$ ,  $R_i$ ,  $R_o$

### 9.3 Experiment Material

**Equipment:** Digital Multi-Meter, DC power supply, Breadboard, Function Generator, Oscilloscope

**Components:** MOSFET, resistors, capacitor

### 9.4 Common source amplifier

Construct the circuit in Fig. 9.1 with a N-channel enhancement MOSFET (2N7000) and  $R_L = 300k\Omega$ . Other components are same as the designed values in pre-lab

**DC Analysis** Let  $v_i$  to be zero (i.e. short it to the ground), use the digital multi-meter to verify the dc operation point  $I_{DQ} = 20mA$ ,  $V_{DSQ} = 4V$ . If the Q-point is not accurate, adjust  $R_2, R_S$  to reduce the deviation.

**AC Analysis: Voltage Gain** Let  $v_i$  to be a sinusoidal signal (1000 Hz, 100mV peak), make sure the output voltage is not distorted with the help of the oscilloscope and record the plot. Now use the digital multi-meter to measure the rms value of  $v_{ib}$  and  $v_o$ . Vary the input voltage amplitude to 80mV, 60mV, 40mV respectively, repeat the last step. Calculate the voltage gain  $A_v = v_o/v_{ib}$  for each case above and fill Table 9.1.

**AC Analysis: Input Resistance** Let  $v_i$  to be a 1000 Hz sinusoidal signal with the amplitude of 100 mV, make sure the output voltage is not distorted with the help of the oscilloscope. Use the digital multi-meter to measure the rms values of  $v_{ib}$  and  $v_i$ , record the two values to calculate the input resistance  $R_i$  and fill Table 9.2.

**AC Analysis: Output Resistance** Let  $v_i$  to be a 1000 Hz sinusoidal signal with the amplitude of 100 mV, make sure the output voltage is not distorted with the help of the oscilloscope. Use the digital multi-meter to measure the rms values of output voltage  $v_o$  when  $R_L = 300k\Omega$  and when  $R_L = 1k\Omega$  respectively, record the two values to calculate the output resistance  $R_o$  and fill Table 9.2.

Table 9.1: Voltage Gain

$V_{ib}$				
$V_o$				
$A_v$				

Table 9.2: Input/output Resistance

$R_s=470K, R_i =$		$R_o=$	
$V_i =$	$V_{ib} =$	$R_L = 300K, V_o =$	$R_L = 1K, V_o =$

## Chapter 10

# Mathematical Circuits Using Op.Amp.

### 10.1 Objective

- To verify Op.Amp. circuits for addition/subtraction/amplification operations
- To verify Op.Amp. circuits for differentiation/integration operations
- To verify Op.Amp. circuits for logarithm/exponentiation operations

### 10.2 Pre-lab Question

In Fig. 10.1,

- Find the output voltages  $v_o$  of each circuit in terms of their input voltages
- Identify the function of each circuit

### 10.3 Experiment Material

**Equipment:** Digital Multi-Meter, DC power supply, Breadboard, Function Generator, Oscilloscope

**Components:** LM741, resistors, capacitors, diodes

### 10.4 Circuit (i)-(iii)

Construct the circuits in Fig. 10.1(i)-(iii) using LM741 and resistors with the supply voltages at  $\pm 12V$ ,

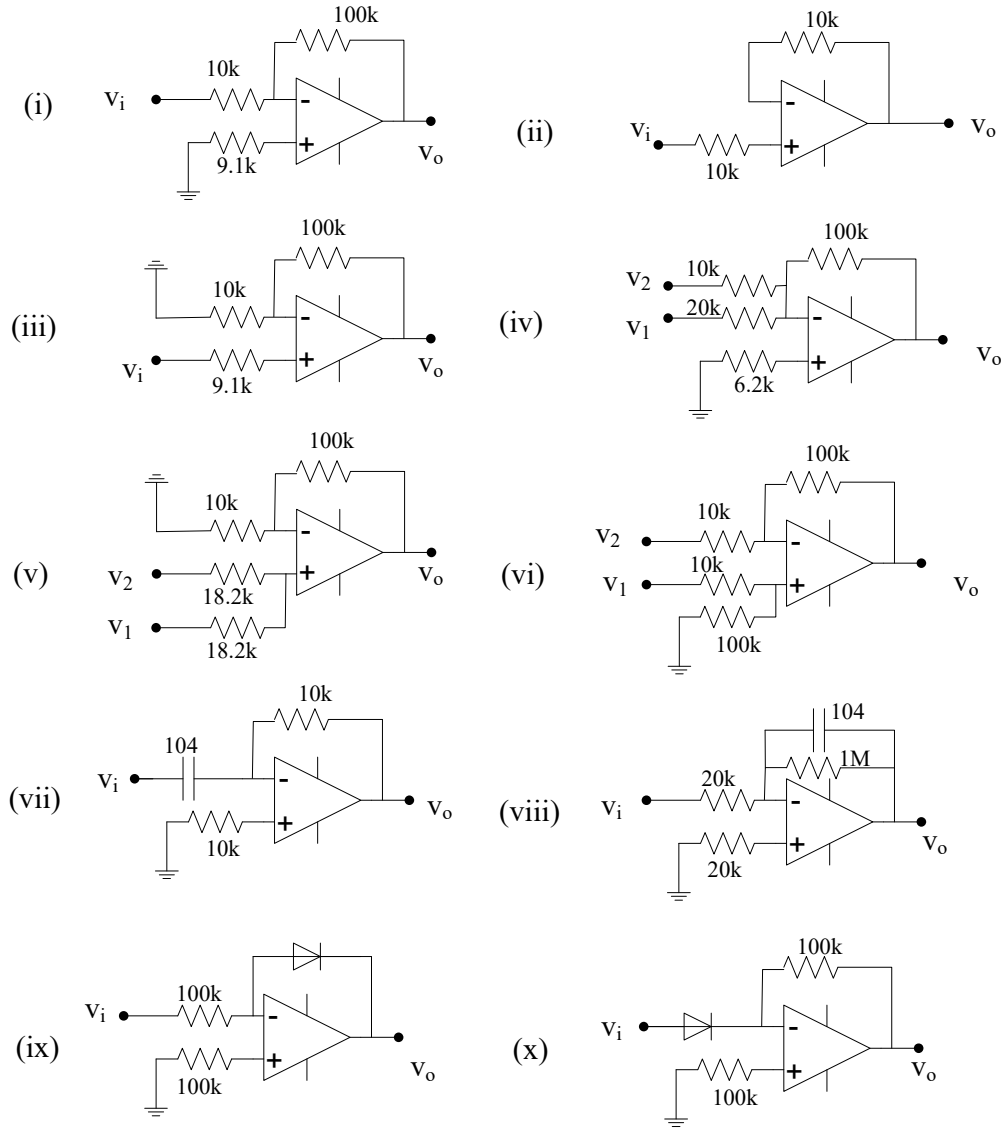


Figure 10.1: Different fundamental Op.Amp. circuits.



- Measure the output voltage  $v_o$  when  $v_i$  varies from 0.1V to 1.5 V, design your own table and record the data of both input and output
- Compare your results with the pre-lab solution and explain any difference

## 10.5 Circuit (iv)-(vi)

Construct the circuits in Fig. 10.1(iv)-(vi) using LM741 and resistors with the supply voltages at  $\pm 12\text{V}$ ,

**Fig. 10.1(iv):** Measure the output voltage  $v_o$ , design your own table and record the data of both input and output

- when  $v_1 = 0.1\text{V}$ ,  $v_2 = 0.2\text{V}$
- when  $v_1 = 0.5\text{V}$ ,  $v_2 = 0.1\text{V}$
- when  $v_1 = 0.1\text{V}$ ,  $v_2 = 0.5\text{V}$
- when  $v_1 = 1.0\text{V}$ ,  $v_2 = 0.4\text{V}$

**Fig. 10.1(v):** Measure the output voltage  $v_o$ , design your own table and record the data of both input and output

- when  $v_1 = 0.1\text{V}$ ,  $v_2 = 0.2\text{V}$
- when  $v_1 = 0.5\text{V}$ ,  $v_2 = 0.3\text{V}$
- when  $v_1 = 0.8\text{V}$ ,  $v_2 = 0.5\text{V}$
- when  $v_1 = 1.0\text{V}$ ,  $v_2 = 1\text{V}$

**Fig. 10.1(vi):** Measure the output voltage  $v_o$ , design your own table and record the data of both input and output

- when  $v_1 = 0.1\text{V}$ ,  $v_2 = 0.4\text{V}$
- when  $v_1 = 0.5\text{V}$ ,  $v_2 = 0.1\text{V}$
- when  $v_1 = 1.0\text{V}$ ,  $v_2 = 0.4\text{V}$

## 10.6 Circuit (vii)-(viii)

Construct the circuits in Fig. 10.1(vii)-(viii) using LM741, capacitor and resistors with the supply voltages at  $\pm 12\text{V}$ ,

**Fig. 10.1(vii):** using the oscilloscope to observe  $v_i$  and  $v_o$  simultaneously

- when  $v_i$  is a sinusoidal signal with peak value at 1V, frequency 200 Hz, find the phase angle of  $v_o$  with  $v_i$  as the reference; vary the frequency of  $v_i$  from 200 Hz to 1kHz, record the change of amplitude and phase angle of  $v_o$  and explain the reason
- when  $v_i$  is a square signal with peak value at 1V, frequency 200 Hz, explain the obtained plot

**Fig. 10.1(viii):** using the oscilloscope to observe  $v_i$  and  $v_o$  simultaneously

- when  $v_i$  is a sinusoidal signal with peak value at 1V, frequency 50 Hz, find the phase angle of  $v_o$  with  $v_i$  as the reference; vary the frequency of  $v_i$  from 50 Hz to 200 Hz, record the change of amplitude and phase angle of  $v_o$  and explain the reason
- when  $v_i$  is a square signal with peak value at 1V, frequency 50 Hz, explain the obtained plot

## 10.7 Circuit (ix)-(x)

Construct the circuits in Fig. 10.1(vii)-(viii) using LM741, 1N4148 and resistors with the supply voltages at  $\pm 12V$ ,

**Fig. 10.1(ix):** let  $v_i$  to be a triangular signal with peak value at 0.5V, frequency 1000 Hz, using the oscilloscope to observe  $v_i$  and  $v_o$  simultaneously, adjust the amplitude of  $v_i$  until the output  $v_o$  has a convex edge when  $v_i$  is increasing and a concave edge when  $v_i$  is decreasing

**Fig. 10.1(x):** let  $v_i$  to be a triangular signal with peak value at 1V, frequency 1000 Hz, using the oscilloscope to observe  $v_i$  and  $v_o$  simultaneously, adjust the amplitude of  $v_i$  until the output  $v_o$  decreases exponentially when  $v_i$  is increasing and increases exponentially when  $v_i$  is decreasing

# Chapter 11

## A Precise Rectifier: part I

### 11.1 Objective

- To verify a precise half-wave rectifier
- To design and verify a precise full-wave rectifier

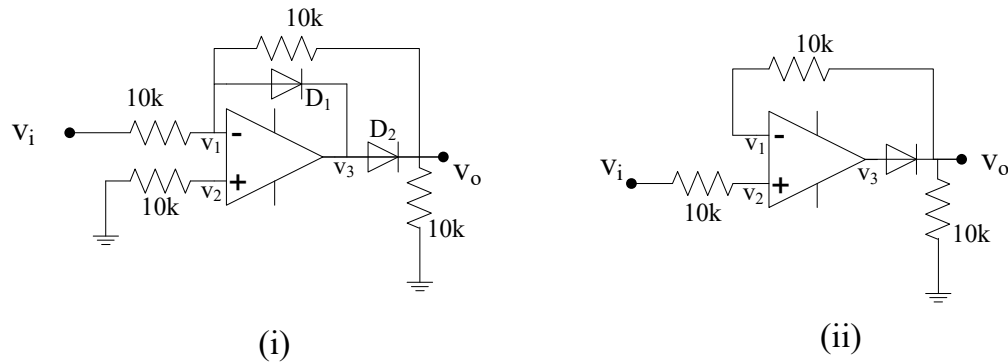


Figure 11.1: Two precise half-wave rectifiers

### 11.2 Pre-lab Question

In Fig. 11.1,

- Find the expressions of  $v_1$ ,  $v_2$ ,  $v_3$ ,  $v_o$  in each circuit in terms of the input voltage and resistors when the Op.Amp is not saturated
- Find the expressions of  $v_1$ ,  $v_2$ ,  $v_3$ ,  $v_o$  in each circuit in terms of the input voltage and resistors when the Op.Amp is saturated

## 11.3 Experiment Material

**Equipment:** Digital Multi-Meter, DC power supply, Breadboard, Function Generator, Oscilloscope

**Components:** Op. Amp, resistors, diodes

## 11.4 The 1<sup>st</sup> precise half-wave rectifier

Construct the circuit in Fig. 11.1(i) using LM741, 1N4148 and resistors with the supply voltages at  $\pm 10\text{V}$ ,

- let  $v_i$  to be a sinusoidal signal with a fixed frequency of 50 Hz, adjust the amplitude of  $v_i$  from 0.1 V to 5 V and use the oscilloscope to observe  $v_i$  and  $v_o$  simultaneously, record the plots and explain what you see
- let  $v_i$  to be a dc voltage signal with amplitude at -10V, -5 V, -1V, 1V, 5 V and 10 V respectively, use the multi-meter to measure  $v_i$ ,  $v_1$ ,  $v_2$ ,  $v_3$ ,  $v_o$  for each case, compare the results with the pre-lab solutions

## 11.5 The 2<sup>nd</sup> precise half-wave rectifier

Construct the circuit in Fig. 11.1(ii) using LM741, 1N4148 and resistors with the supply voltages at  $\pm 10\text{V}$ ,

- let  $v_i$  to be a sinusoidal signal with a fixed frequency of 50 Hz, adjust the amplitude of  $v_i$  from 0.1 V to 5 V and use the oscilloscope to observe  $v_i$  and  $v_o$  simultaneously, record the plots and explain what you see
- let  $v_i$  to be a dc voltage signal with amplitude at -10V, -5 V, -1V, 1V, 5 V and 10 V respectively, use the multi-meter to measure  $v_i$ ,  $v_1$ ,  $v_2$ ,  $v_3$ ,  $v_o$  for each case, compare the results with the pre-lab solutions

## Chapter 12

# A Precise Rectifier: part II

### 12.1 Objective

- To verify two different precise full-wave rectifiers

### 12.2 Pre-lab Question

In Fig. 12.1,

- Find the expressions of  $v_1, v_2, v_3, v_4, v_5, v_o$  in each circuit in terms of the input voltage and resistors when the Op.Amp is not saturated
- Find the expressions of  $v_1, v_2, v_3, v_4, v_5, v_o$  in each circuit in terms of the input voltage and resistors when the Op.Amp is saturated

### 12.3 Experiment Material

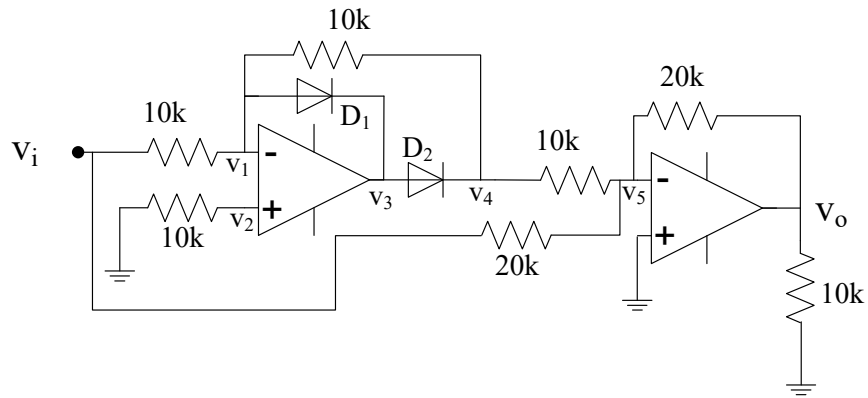
**Equipment:** Digital Multi-Meter, DC power supply, Breadboard, Function Generator, Oscilloscope

**Components:** Op. Amp, resistors, diodes

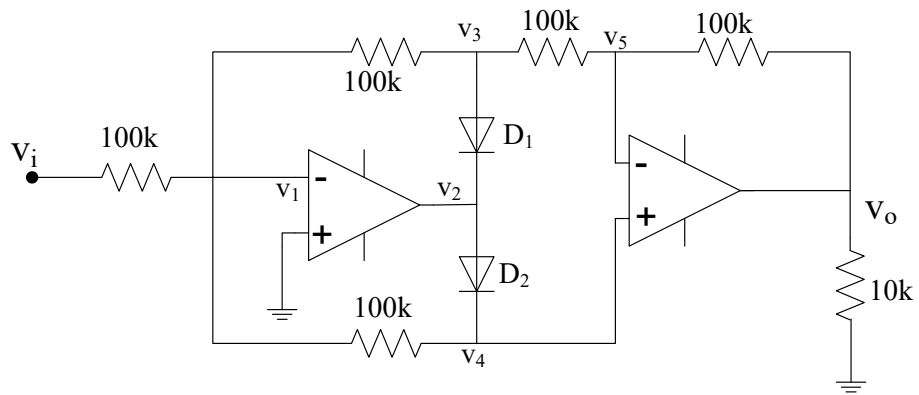
### 12.4 The 1<sup>st</sup> precise full-wave rectifier

Construct the circuit in Fig. 12.1(i) using LM741, 1N4148 and resistors with the supply voltages at  $\pm 10V$ ,

- let  $v_i$  to be a sinusoidal signal with a fixed frequency of 200 Hz, adjust the amplitude of  $v_i$  from 0.1 V to 5 V and use the oscilloscope to observe  $v_i$  and  $v_o$  simultaneously, record the plots and explain what you see



(i)



(ii)

Figure 12.1: Two precise full-wave rectifiers.

- let  $v_i$  to be a dc voltage signal with amplitude at -12V, -5 V, -1V, 1V, 5 V and 12 V respectively, use the multi-meter to measure  $v_i$ ,  $v_1$ ,  $v_2$ ,  $v_3$ ,  $v_4$ ,  $v_5$ ,  $v_o$  for each case, compare the results with the pre-lab solutions

## 12.5 The 2<sup>nd</sup> precise full-wave rectifier

Construct the circuit in Fig. 12.1(ii) using LM741, 1N4148 and resistors with the supply voltages at  $\pm 10V$ ,

- let  $v_i$  to be a sinusoidal signal with a fixed frequency of 200 Hz, adjust the amplitude of  $v_i$  from 0.1 V to 5 V and use the oscilloscope to observe  $v_i$  and  $v_o$  simultaneously, record the plots and explain what you see
- let  $v_i$  to be a dc voltage signal with amplitude at -12V, -5 V, -1V, 1V, 5 V and 12 V respectively, use the multi-meter to measure  $v_i$ ,  $v_1$ ,  $v_2$ ,  $v_3$ ,  $v_4$ ,  $v_5$ ,  $v_o$  for each case, compare the results with the pre-lab solutions

## Chapter 13

# Design Question: A precise full-wave rectifier

### 13.1 Objective

- To design a op-amp based precise full-wave rectifier

### 13.2 Requirements

Based on the circuit in Fig. 11.1, design a full-wave rectifier and construct it using LM741, 1N4148 and resistors with the supply voltages at  $\pm 10\text{V}$ ,

- The designed circuit can not be same as any of Fig. 12.1.
- Explain the principle of the designed circuit, build and verify the function of the circuit in the lab